

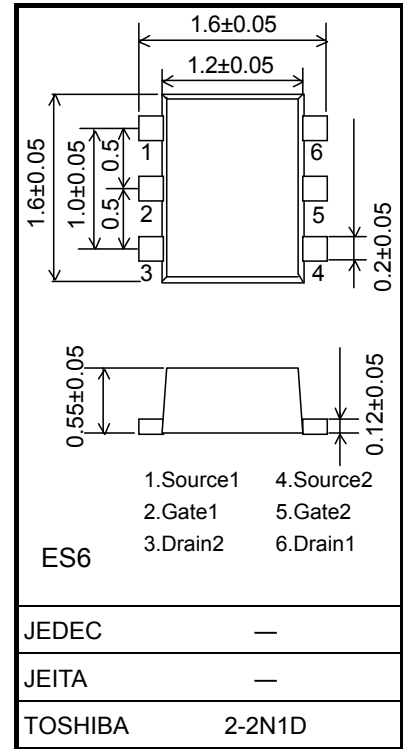
TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

SSM6N37FE

- High-Speed Switching Applications
- Analog Switching Applications

- 1.5-V drive
- Suitable for high-density mounting due to compact package
- Low ON-resistance
 - $R_{DS(ON)} = 5.60 \Omega$ (max) (@ $V_{GS} = 1.5 V$)
 - $R_{DS(ON)} = 4.05 \Omega$ (max) (@ $V_{GS} = 1.8 V$)
 - $R_{DS(ON)} = 3.02 \Omega$ (max) (@ $V_{GS} = 2.5 V$)
 - $R_{DS(ON)} = 2.20 \Omega$ (max) (@ $V_{GS} = 4.5 V$)

単位: mm



Weight: 3.0 mg (typ.)

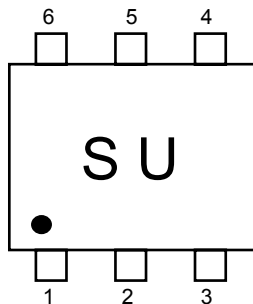
Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit
Drain–source voltage	V_{DSS}	20	V
Gate–source voltage	V_{GSS}	± 10	V
Drain current	DC	I_D	250
	Pulse	I_{DP}	500
Drain power dissipation	P_D (Note 1)	150	mW
Channel temperature	T_{ch}	150	°C
Storage temperature	T_{stg}	-55 to 150	°C

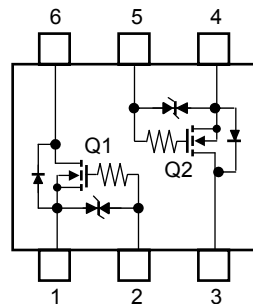
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating
 Mounted on an FR4 board
 (25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 0.135 mm² × 6)

Marking



Equivalent Circuit (top view)



Start of commercial production
 2009-12

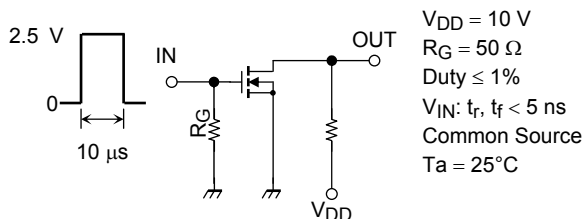
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	20	—	—	V	
	$V_{(BR)DSX}$	$I_D = 1 \text{ mA}, V_{GS} = -10 \text{ V}$	12	—	—		
Drain cutoff current	I_{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$	—	—	1	μA	
Gate leakage current	I_{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$	—	—	± 1	μA	
Gate threshold voltage	V_{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$	0.35	—	1.0	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3 \text{ V}, I_D = 100 \text{ mA}$ (Note 2)	0.14	0.28	—	S	
Drain-source ON-resistance	$R_{DS(ON)}$	$I_D = 100 \text{ mA}, V_{GS} = 4.5 \text{ V}$ (Note 2)	—	1.65	2.20	Ω	
		$I_D = 50 \text{ mA}, V_{GS} = 2.5 \text{ V}$ (Note 2)	—	2.16	3.02		
		$I_D = 20 \text{ mA}, V_{GS} = 1.8 \text{ V}$ (Note 2)	—	2.66	4.05		
		$I_D = 10 \text{ mA}, V_{GS} = 1.5 \text{ V}$ (Note 2)	—	3.07	5.60		
Input capacitance	C_{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	—	12	—	pF	
Output capacitance	C_{oss}		—	5.5	—		
Reverse transfer capacitance	C_{rss}		—	4.1	—		
Switching time	Turn-on time	t_{on}	$V_{DD} = 10 \text{ V}, I_D = 100 \text{ mA}$ $V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 50 \Omega$	—	18	—	ns
	Turn-off time	t_{off}		—	36	—	
Drain-source forward voltage	V_{DSF}	$I_D = -250 \text{ mA}, V_{GS} = 0 \text{ V}$ (Note 2)	—	-0.9	-1.2	V	

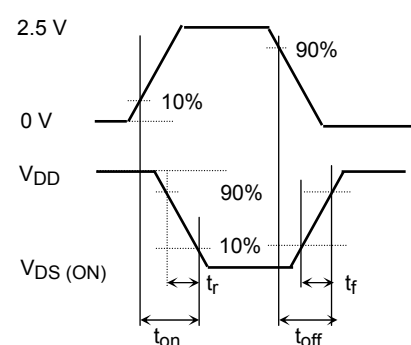
Note 2: Pulse test

Switching Time Test Circuit (Q1, Q2 Common)

(a) Test Circuit



(b) V_{IN}



(c) V_{OUT}

Precaution

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to be low (1mA for the SSM6N37FE). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

Take this into consideration when using the device.

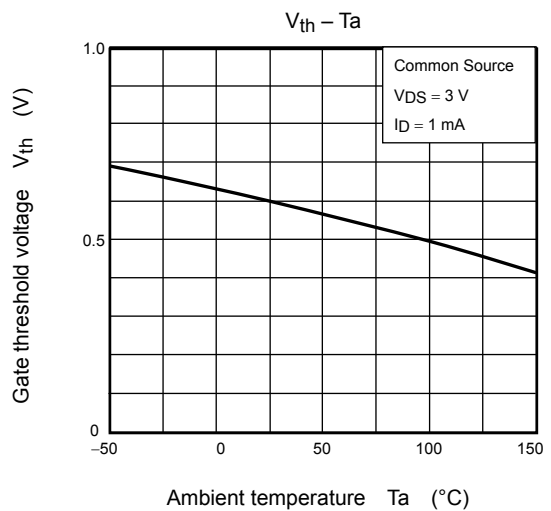
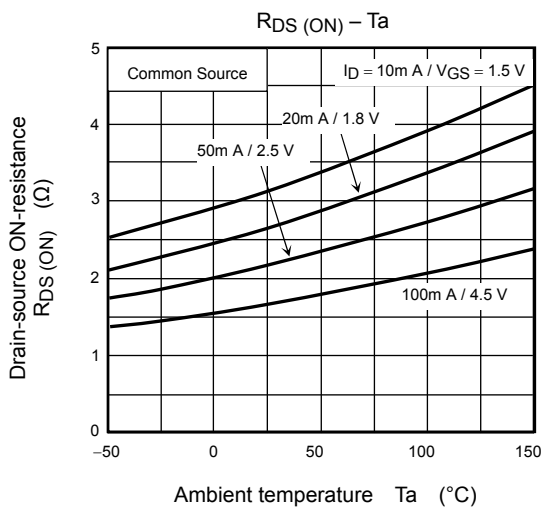
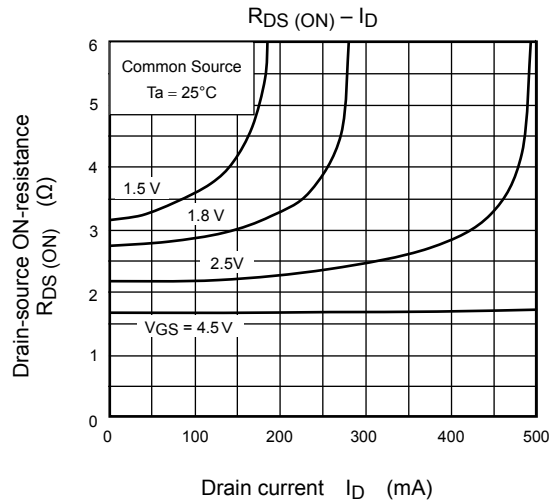
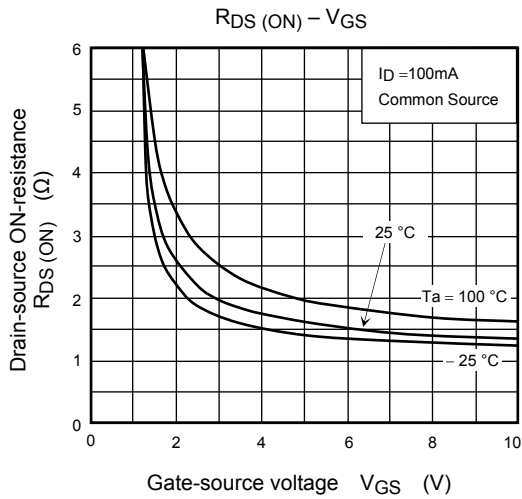
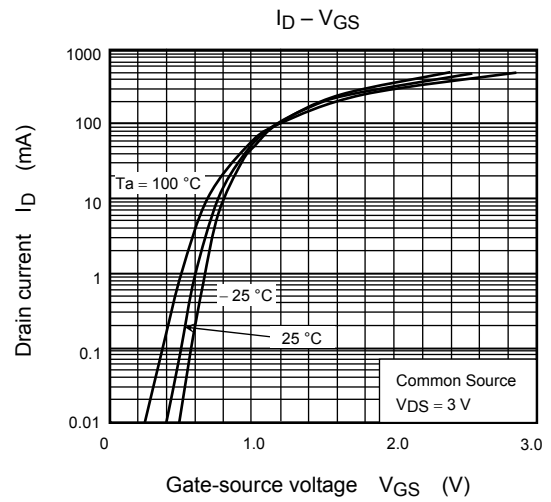
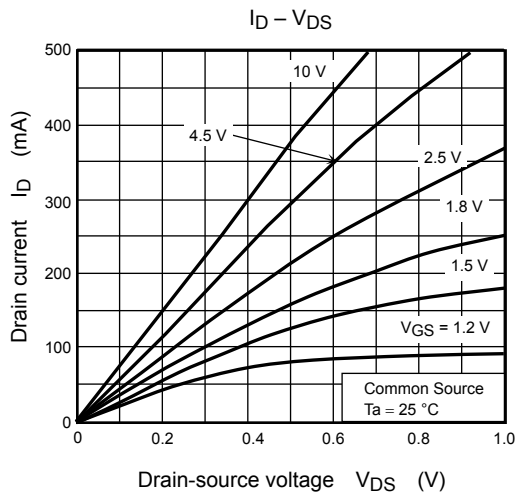
Do not use this device under avalanche mode. It may cause the device to break down.

Handling Precaution

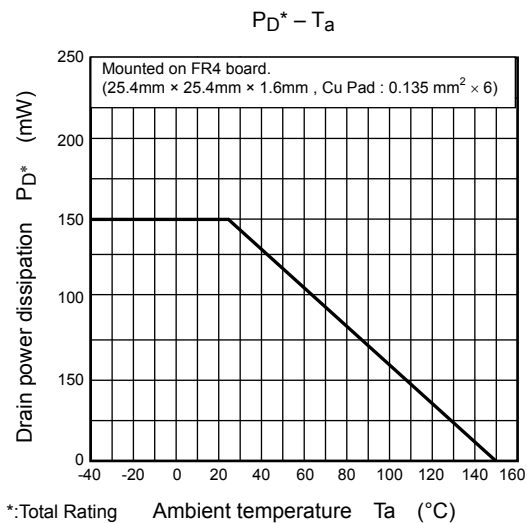
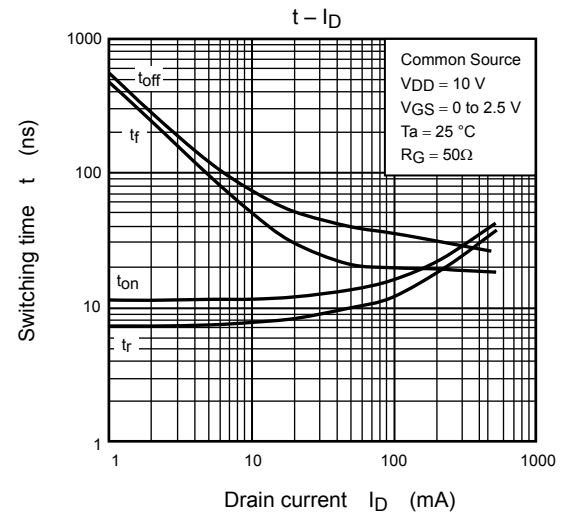
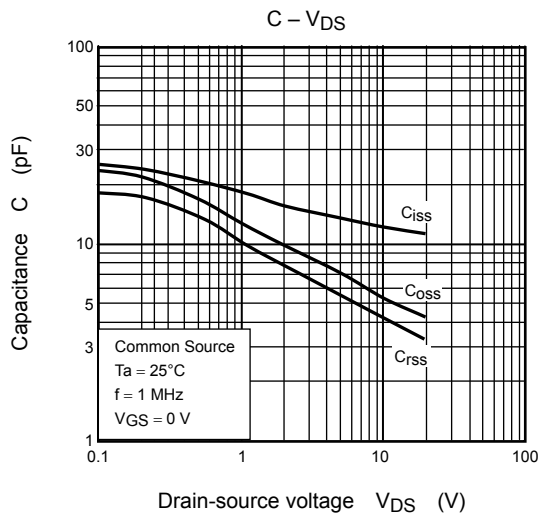
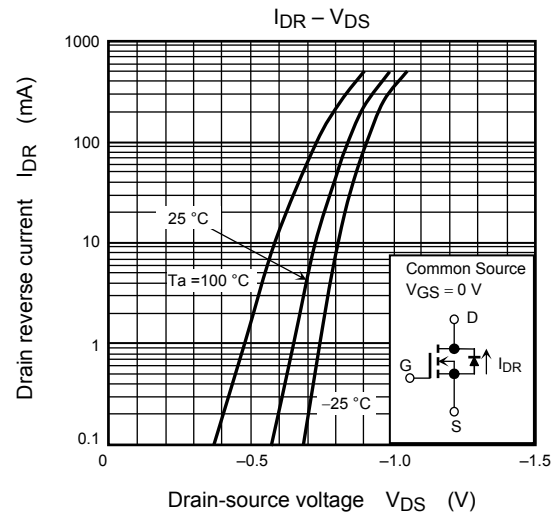
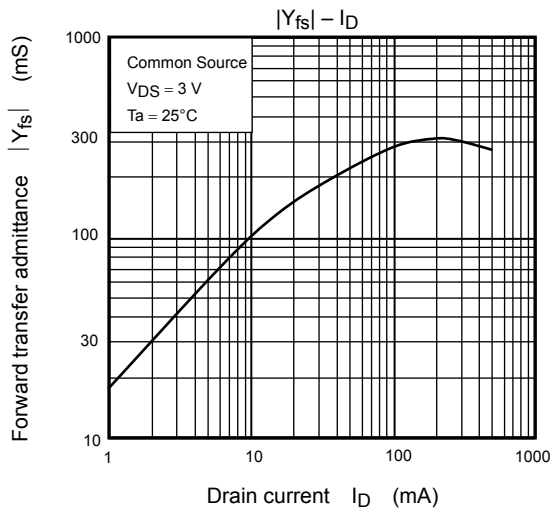
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

Thermal resistance $R_{th(j-a)}$ and drain power dissipation P_D vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration.

(Q1, Q2 Common)



(Q1, Q2 Common)



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